Name: **Dr JBO** 

Student ID Number: Model Answer

Section: 01A/01B

01B

EEEB273 - Quiz 1 [Question Set 1]

SEMESTER 1, ACADEMIC YEAR 2011/2012

Date: 23 May 2011

Lecturer: Dr. Jamaludin Bin Omar

# **Question:**

Refer to **Figure 1**. All transistors are matched.

The circuit parameters are:  $V^+ = 7.5 \text{ V}$  and  $V^- = -7.5 \text{ V}$ .

The transistor parameters are:  $\beta = 100$ ,  $V_{BE}$  (on) = 0.6 V, and  $V_A = 150$  V.

Given  $I_{B2} = 8 \mu A$ .

(a) Design a two-transistor current source using all the parameters given above.

[8 marks]

(b) Find the output resistance ( $R_0$ ) of the two-transistor current source.

[2 marks]

Show clearly all calculations as marks are given according to this.

### **Answer:**

-		
$I_O = I_{C2}$	$=\beta I_{B2}$	[1]
	$=(100)(8\mu)$	[1]
	= 0.8  mA	[0.5]
$I_{REF}$	$=I_O(1+2/\beta)$	[1]
	= (0.8m)(1 + 2/100)	[1]
	= 0.816  mA	[0.5]
$R_1$	$= (V^+ - V_{BE} - V^-) / I_{REF}$	[1.5]
	= (7.5 - 0.6 - (-7.5)) / (0.816m)	
	$= 17.647 \text{ k}\Omega$	[0.5]
$R_{O}$	$=V_A/I_O$	[1]
	= (150) / (0.8m)	[0.5]
	$= 187.5 \text{ k}\Omega$	[0.5]

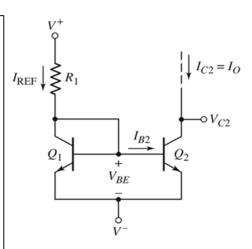


Figure 1

Name: **Dr JBO** 

Student ID Number: Model Answer

Section: 05A / 05B

Lecturer: Dr. Jamaludin Bin Omar

EEEB273 - Quiz 1 [Question Set 1]

SEMESTER 1, ACADEMIC YEAR 2011/2012

Date: 23 May 2011

# **Question:**

Refer to **Figure 1**. All transistors are matched.

The circuit parameters are:  $V^+ = 10 \text{ V}$  and  $V^- = -10 \text{ V}$ .

The transistor parameters are:  $\beta = 120$ ,  $V_{BE}$  (on) = 0.6 V, and  $V_A = 100$  V.

Given  $I_{B2} = 8 \mu A$ .

(c) Design a two-transistor current source using all the parameters given above.

[8 marks]

(d) Find the output resistance  $(R_0)$  of the two-transistor current source.

[2 marks]

Show clearly all calculations as marks are given according to this.

#### **Answer:**

$I_O = I_{C2}$	$=\beta I_{B2}$	[1]	
	$=(120)(8\mu)$	[1]	
	= 0.96  mA	[0.5]	
$I_{REF}$	$=I_O(1+2/\beta)$	[1]	
	$= (0.96 \mathrm{m})(1 + 2/120)$	[1]	
	= 0.976  mA	[0.5]	
$R_1$	$= (V^+ - V_{BE} - V^-) / I_{REF}$	[1.5]	
	= (10 - 0.6 - (-10)) / (0.976m)		[1]
	$= 19.877 \text{ k}\Omega$	[0.5]	
$R_O$	$=V_A/I_O$	[1]	
	= (100) / (0.96m)	[0.5]	
	$= 104.167 \text{ k}\Omega$	[0.5]	

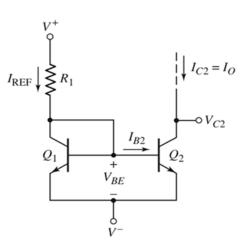


Figure 1

Name: **Dr JBO** 

Student ID Number: Model Answer

Section: 05A / 05B

Lecturer: Dr. Jamaludin Bin Omar

EEEB273 - Quiz 1 [Question Set 2] SEMESTER 1, ACADEMIC YEAR 2011/2012

Date: 23 May 2011

## **Question:**

Refer to **Figure 1**. All transistors are matched.

The circuit parameters are:  $V^+ = 7.5 \text{ V}$  and  $V^- = -7.5 \text{ V}$ .

The transistor parameters are:  $\beta = 100$ ,  $V_{BE}$  (on) = 0.6 V, and  $V_A = 120$  V.

Given  $I_{B2} = 10 \,\mu\text{A}$ .

(e) Design a two-transistor current source using all the parameters given above.

[8 marks]

(f) Find the output resistance ( $R_0$ ) of the two-transistor current source.

[2 marks]

Show clearly all calculations as marks are given according to this.

### **Answer:**

$I_O = I_{C2}$	= $\beta I_{B2}$ = $(100)(10\mu)$ = 1.0 mA	[1] [1] [0.5]	
I <sub>REF</sub>	= $I_O (1 + 2/\beta)$ = $(1.0 \text{m})(1 + 2/100)$ = $1.02 \text{ mA}$	[1] [1] [0.5]	
$R_1$	= $(V^+ - V_{BE} - V^-) / I_{REF}$ = $(7.5 - 0.6 - (-7.5)) / (1.0)$ = $14.118 \text{ k}\Omega$	[1.5] (2m) [0.5]	[1]
Ro	= $V_A / I_O$ = (120) / (1.0m) = 120.0 k $\Omega$	[1] [0.5] [0.5]	

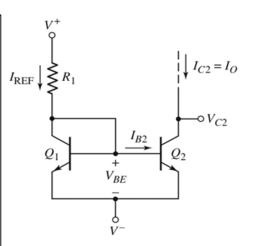


Figure 1